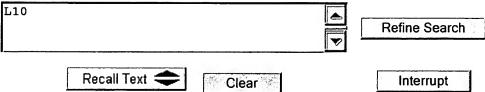
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Set Name side by side	Query	<u>Hit</u> <u>Count</u>	<u>Set</u> <u>Name</u> result set
DB=P	GPB, USPT, USOC, EPAB, JPAB, DWPI, TDBD; PLUR=YES; OP=ADJ		
<u>L10</u>	438/792.ccls.	269	<u>L10</u>
<u>L9</u>	438/763.ccls.	2928	<u>L9</u>
<u>L8</u>	L6 and ((second near3 nitride) same (concentration or ratio))	7	<u>L8</u>
<u>L7</u>	L6 and (second near3 nitride)	63	<u>L7</u>
<u>L6</u>	L5 and (copper same silicon nitride)	179	<u>L6</u>
<u>L5</u>	L4 and plasma	481	<u>L5</u>
<u>L4</u>	L3 and ((barrier or dielectric or insulator) same silicon nitride)	481	<u>L4</u>
<u>L3</u>	L2 and plasma	754	<u>L3</u>
<u>L2</u>	L1 and (silicon nitride and (silicon or nitride) near (concentration or ratio))	955	<u>L2</u>
<u>L1</u>	copper	784360	<u>L1</u>

END OF SEARCH HISTORY